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Quantum Dots and Nanostructures: Growth, Characterization, and Modeling XV

**Diana L. Huffaker
Holger Eisele**
Editors

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Contents

v	<i>Authors</i>
vii	<i>Conference Committee</i>

NANOWIRE: LASERS AND EMITTERS

10543 03	Recent progress in nanowire quantum-dot lasers (Invited Paper) [10543-2]
10543 06	Numerical analysis of nanowire surface recombination using a three-dimensional transient model [10543-5]

NANOSTRUCTURES: GROWTH AND ANALYSIS

10543 09	Impact of phosphorus ion implantation on the material and optical properties of InAs/GaAs quantum dots [10543-8]
10543 0A	Electrical characteristics of silicon nanowires solar cells with surface roughness [10543-9]

NANOWIRES: OPTOELECTRONICS AND PLASMONICS

10543 0I	Engineering III-V nanowires for optoelectronics: from epitaxy to terahertz photonics (Invited Paper) [10543-17]
----------	--

QUANTUM DOTS: EPITAXY TO APPLICATION

10543 0K	Droplet etching during semiconductor epitaxy for single and coupled quantum structures (Invited Paper) [10543-20]
10543 0L	Quantum dot growth on (111) and (110) surfaces using tensile-strained self-assembly (Invited Paper) [10543-21]
10543 0M	Ultrafast and nonlinear dynamics of InAs/GaAs semiconductor quantum dot lasers (Invited Paper) [10543-22]
10543 0N	Plasmonic induced transparency in graphene oxide quantum dots [10543-23]

POSTER SESSION

- 10543 OR **Co-relation of theoretical simulation with experimental results for InAs quantum-dot heterostructures with different capping material** [10543-29]
- 10543 OS **Highly efficient InAs/InGaAs quantum dot-in-a-well heterostructure validated with theoretically simulated model** [10543-30]
- 10543 OU **Effect of various capping layer on the hydrostatic and biaxial strain of InAs QDs in x (100) and z (001) direction** [10543-32]
- 10543 OW **Application of silver nanostructures deposited on silicon in SERS for detection of pyridine** [10543-34]
- 10543 OX **Polymer-coated silicon nanoparticle synthesis for optical applications** [10543-35]
- 10543 IO **Deposition of cadmium sulfide and cadmium selenide thin films using chemical bath deposition technique** [10543-38]

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Abel Razek, Sara, 0W	Singh, P. K., 0R, 0S
Adeyemo, Stephanie O., 0I	Sousa, Erik, 10
Arakawa, Yasuhiko, 03	Subrahmanyam, N. B. V., 09
Arsenijevic, D., 0M	Swillam, Mohamed A., 0A, 0W, 0X
Baig, Sarwat A., 0I	Tan, H. Hoe, 0I
Bhagwat, P., 09	Tatebayashi, Jun, 03
Bhatt, M., 0R, 0S	Tharwat, C., 0X
Bimberg, D., 0M	Upadhyay, S., 09
Bishel, David, 10	Uswachoke, Chawit, 0I
Boland, Jessica L., 0I	Wong-Leung, Jennifer, 0I
Chakrabarti, Subhananda, 09, 0R, 0S, 0U	Zhang, Liangmin, 10
Chavan, Vinayak, 09, 0U	Zocher, M., 0K
Cheung, William, 10	
Damry, Djamshid A., 0I	
Das, Debabrata, 0U	
Davies, Christopher L., 0I	
Dong, Lifeng, 10	
D'Souza, Francis, 0N	
Dubey, S., 0R, 0S	
Ghadi, H., 0R, 0S	
Girgis, E., 0X	
Grillot, Frédéric, 0M	
Hameed, Mohamed Farhat O., 0A	
Hansen, W., 0K	
Herz, Laura M., 0I	
Heyn, Ch., 0K	
Huang, H., 0M	
Huffaker, Diana L., 06	
Hussein, Mohamed, 0A	
Jagadish, C., 0I	
Johnston, Michael B., 0I	
Joyce, Hannah J., 0I	
Karna, Sanjay, 0N	
Küster, A., 0K	
Liang, Baolai, 06	
Linares-Garcia, Anthony, 10	
Mahat, Meg, 0N	
Mandal, A., 09	
Mini, Joseph, 10	
Mondragon, Ivan, 10	
Montes, Salvador, 10	
Neogi, Arup, 0N	
Obayya, S. S. A., 0A	
Panda, Debiprasad, 0U	
Ren, Dingkun, 06	
Rong, Zixuan, 06	
Rostovtsev, Yuri, 0N	
Saha, Jhuma, 0U	
Simmonds, Paul J., 0L	

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- 1 Nanowire: Lasers and Emitters
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Juan Salvador Dominguez Morales, Tyndall National Institute (Ireland)
- 3 Nanowires: Growth and Characterization
Jun Tatebayashi, Osaka University (Japan)

- 4 Nanowires: Optoelectronics and Plasmonics
Baolai Liang, California NanoSystems Institute (United States)
- 5 Quantum Dots: Epitaxy to Application
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